

STPIC6D595

Power logic 8-bit shift register

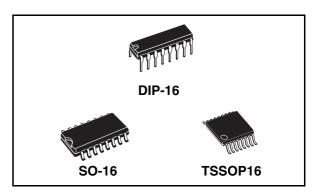
Features

- Low R_{DS(on)}: 4Ω typ
- Eight 100mA DMOS outputs
- 250mA current limit capability
- Device are cascadable
- Low power consumption

Description

This STPIC6D595 is a monolithic, mediumvoltage, low current power 8-bit shift register designed for use in systems that require relatively moderate load power such as LEDs.

The device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Data transfers through both the shift and storage register clock (SRCK) and the register clock (RCK), respectively. The device transfers data out the serial output (SER OUT) port on the rising edge of SRCK. The storage register transfers data to the output buffer when shift register clear (CLR) is high. When $\overline{\text{CLR}}$ is low, the input shift register is cleared. When output enable $(\overline{\text{G}})$ is held high, all data in the output buffer is held low and all drain output are off. When G is held low, data from the storage register is transparent to the output buffer.



When data in the output buffers is low, the DMOS transistor outputs are off. When data is high, the DMOS transistor outputs have sink-current capability. The SER OUT allows for cascading of the data from the shift register to additional devices.

Output are low-side, open-drain DMOS transistors with output ratings of 20V and 120mA continuous sink-current capability. Each output provides a 250 mA maximum current limit at $T_{\rm C}=25^{\circ}{\rm C}.$ The current limit decreases as the junction temperature increases for additional device protection. The device also provides up to 2.0KV of ESD protection when tested using the human-body model.

The STPIC6D595 is characterized for operation over the operating case temperature range of -40°C to 125°C.

Table 1. Device summary

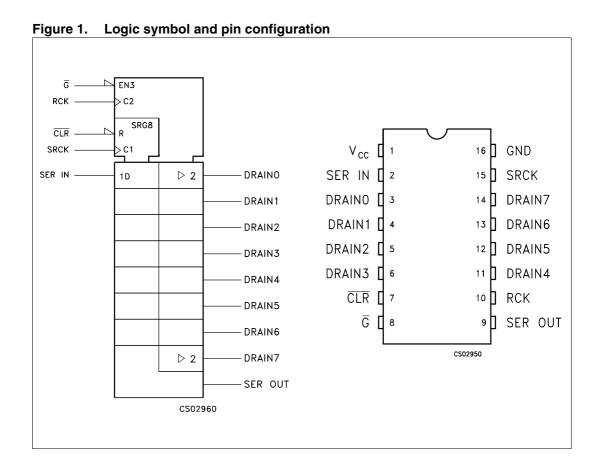
Table 11 Bevies summary								
Order code	Package	Packaging						
STPIC6D595M	SO-16 (Tube)	50 parts per tube / 20 tube per box						
STPIC6D595MTR	SO-16 (Tape & Reel)	2500 parts per reel						
STPIC6D595TTR	TSSOP16 (Tape & Reel)	2500 parts per reel						
STPIC6D595B1	DIP-16	2500 parts per reel						

Contents STPIC6D595

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1 Logic symbol and pin configuration



Maximum rating STPIC6D595

2 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

2.1 Absolute maximum ratings

Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CC}	Logic supply voltage (See Note 1)	7	V
V _I	Logic input voltage range	-0.3 to 7	V
V_{DS}	Power DMOS drain to source voltage (See Note 2)	20	V
I _{DS}	Continuous source to drain diode anode current	250	mA
I _D	Pulsed drain current, each output, all output ON $(T_C = 25^{\circ}C)$	250	mA
I _D	Continuous current, each output, All Output ON $(T_C = 25^{\circ}C)$	100	mA
I _D	Peak drain current single output (T _C = 25°C) (See <i>Note 3</i>)	250	mA
P_{d}	Continuous total dissipation (T _C ≤ 25°C)	1087	mW
P_{d}	Continuous total dissipation (T _C = 125°C)	217	mW
T _J	Operating virtual junction temperature range	-40 to +150	°C
T _C	Operating case temperature range	-40 to +125	°C
T _{stg}	Storage temperature range	-65 to +150	°C
T _L	Lead temperature 1.6mm (1/16inch) from case for 10 seconds	260	°C

2.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{th(JA)}$	Thermal resistance junction-ambient	115	°C/W

STPIC6D595 Maximum rating

2.3 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Parameter	Min	Max	Unit
V _{CC}	Logic supply voltage	4.5	5.5	V
V _{IH}	High level input voltage	0.85V _{CC}	V _{CC}	V
V _{IL}	LoW Level Input Voltage	0	0.15V _{CC}	V
I _{DP}	Pulse drain output current (T _C = 25°C, V _{CC} = 5V,all outputs ON) (see <i>Note 3</i> , <i>Note 4</i>)		250	mA
t _{su}	Set-up Time, SER IN High Before SRCK ↑ (see <i>Figure 3</i> and <i>Figure 7</i>)	20		ns
t _h	Hold Time, SER IN High Before G ↑ (see Figure Figure 3, Figure 6, Figure 7)	20		ns
t _W	Pulse duration (see Figure 7)	40		ns
T _C	Operating case temperature	-40	125	°C

Electrical characteristics STPIC6D595

3 Electrical characteristics

3.1 DC characteristics

Table 5. DC characteristics ($V_{CC} = 5V$, $T_{C} = 25^{\circ}C$, unless otherwise specified.)

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{(BR)DSX}	Drain-to-source breakdown voltage	I _D = 1mA			20	٧
V _{OH}	High level output	$I_{OH} = -20 \mu AV_{CC} = 4.5V$	4.4	4.49		V
VOH	voltage SER OUT	$I_{OH} = -4 \text{ mAV}_{CC} = 4.5 \text{V}$	4			V
V _{OL}	Low level output	$I_{OH} = 20 \ \mu AV_{CC} = 4.5V$		1	100	mV
VOL	voltage SER OUT	$I_{OH} = 4 \text{ mAV}_{CC} = 4.5 \text{V}$		145	300	mV
I _{IH}	High level input current	$V_{CC} = 5.5VV_I = V_{CC}$		1	100	nA
I _{IL}	Low level input current	$V_{CC} = 5.5VV_I = 0$		-1	-100	nA
Icc	Logic supply current	$V_{CC} = 5.5V$ All outputs OFF or ON		23	40	μА
I _{CC(FRQ)}	Logic supply current at frequency	$f_{SRCK} = 5MHzC_L = 30pF$ All outputs OFF (See <i>Figure 5</i> , ⁽¹⁾)		70	250	μА
I _N	Nominal current $ \begin{array}{c} V_{DS(on)} = 0.5 VI_{N} = I_{D} \\ T_{C} = 85^{\circ}C \\ (See \ \textit{Note 4}, \ \textit{Note 5}, \ \textit{Note 6}) \\ (1) \end{array} $			120	200	μΑ
		$V_{DS} = 20VV_{CC} = 5.5V$		0.02	1	μА
I _{DSX}	Off-state drain current	$V_{DS} = 20VV_{CC} = 5.5V \text{ or } 0V$ $T_C = 125^{\circ}C$		0.5	1	μА
	Static drain source on	$I_D = 50 \text{mAV}_{CC} = 4.5 \text{V}$		3.4	4	Ω
R _{DS(on)}	Static drain source on state resistance (See <i>Note 4</i> , and	$I_D = 50 \text{mAV}_{CC} = 4.5 \text{V}$ $T_C = 125 ^{\circ}\text{C}$		4.8	6	Ω
	Note 5)	$I_D = 100 \text{mAV}_{CC} = 4.5 \text{V}$		3.5	6	Ω

^{1.} Not tested, specified by design

Switching characteristics 3.2

Table 6. Switching characteristics ($V_{CC} = 5V$, $T_C = 25$ °C, unless otherwise specified.)

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
t _{PHL}	Propagation delay time, high to low level output from \overline{G}			19	30	ns
t _{PLH}	Propagation delay time, low to high level output from $\overline{\mathbf{G}}$			46	70	ns
t _{PHL-SDO}	Propagation delay time, Clock to SDO			14	20	ns
t _{PLH-SDO}	Propagation delay time, Clock to SDO	O 00mFl 75mA		14	20	ns
t _{PLH-R_O}	Propagation delay low to high level RCK to OUT	$C_L = 30 \text{pFI}_D = 75 \text{mA}$ (See Figure 3, Figure 4, Figure 5,		62	90	ns
t _{PHL-R_O}	Propagation delay high to low level RCK to OUT	Figure 6,)		13	18	ns
t _{PLH-S_SO}	Propagation delay low to high level SCK to SDO			14	20	ns
t _{PHL-S_SO}	Propagation delay high to low level SCK to SDO			14	20	ns
t _r	Rise time, drain output			20	30	ns
t _f	Fall time, drain output			15	20	ns

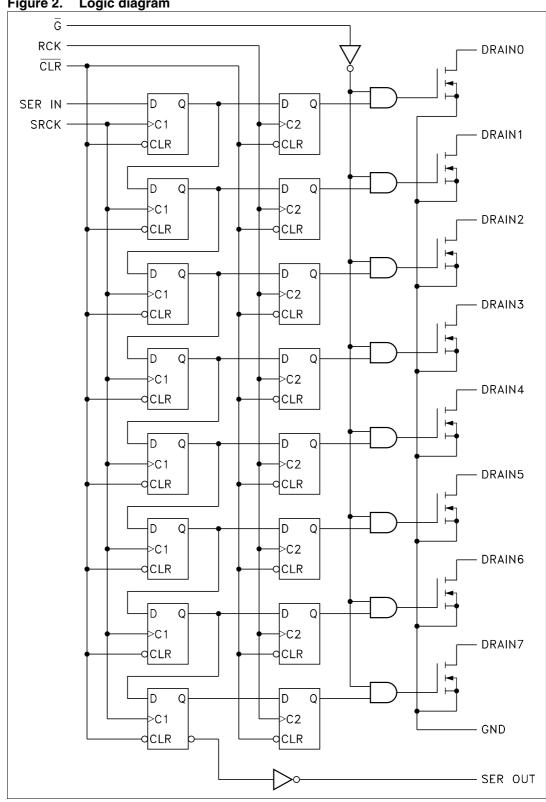
Note:

- All voltage value are with respect to GND
- Each power DMOS source is internally connected to GND 2
- Pulse duration \leq 100 μ s and duty cycle \leq 2% 3
- 4 Technique should limit T_J - T_C to 10°C maximum
- These parameters are measured with voltage sensing contacts separate from the current-5 carrying contacts.
- Nominal Current is defined for a consistent comparison between devices from different sources. It is the current that produces a voltage drop of 0.5V at T_C = 85°C.

Logic diagram STPIC6D595

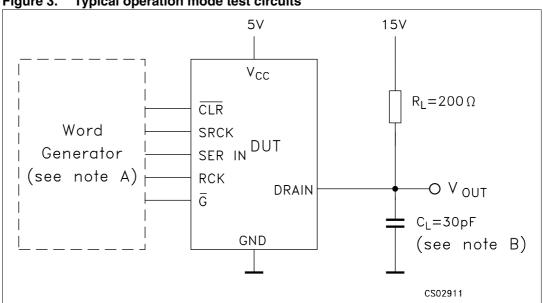
Logic diagram 4



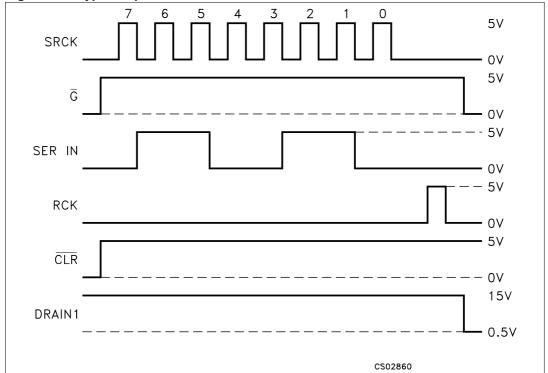


Typical operating circuit 5

Figure 3. Typical operation mode test circuits







A) The word generator has the following characteristics: $t_r \le 10$ ns, $t_t \le 10$ ns, $t_W = 300$ ns, Note: pulse repetition rate (PRR) = 5KHz, $Z_O = 50\Omega$

B) C_1 includes probe and jig capacitance.

Figure 5. Typical operation mode test circuits

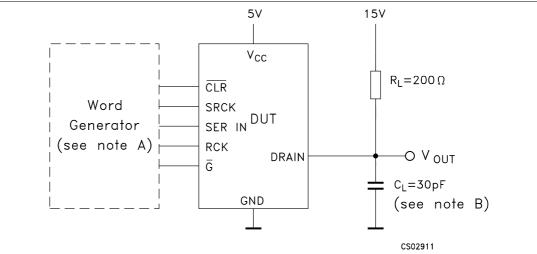
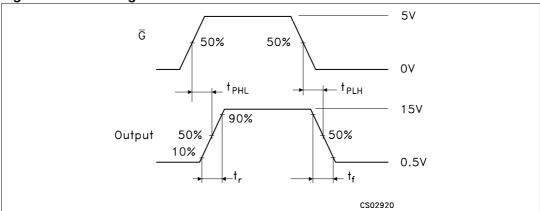


Figure 6. Switching time waveform



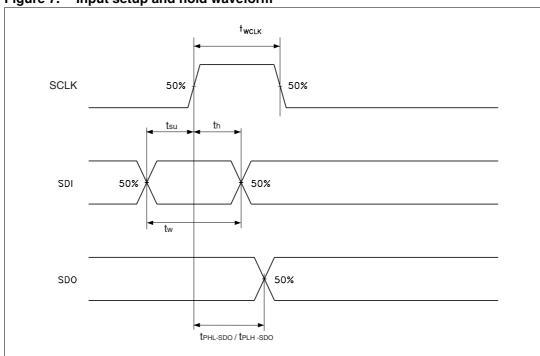


Figure 7. Input setup and hold waveform

Note: 1 A) The word generator has the following characteristics: $t_r \le 10$ ns, $t_f \le 10$ ns, $t_W = 300$ ns, pulse repetition rate (PRR) = 5KHz, $Z_O = 50\Omega$

2 B) C_L includes probe and jig capacitance.

Figure 8. Input equivalent circuit

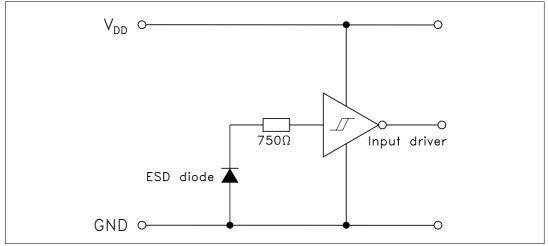
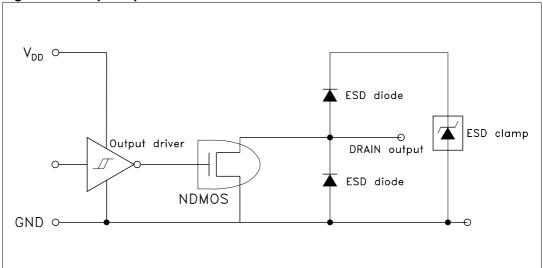


Figure 9. Output equivalent circuit



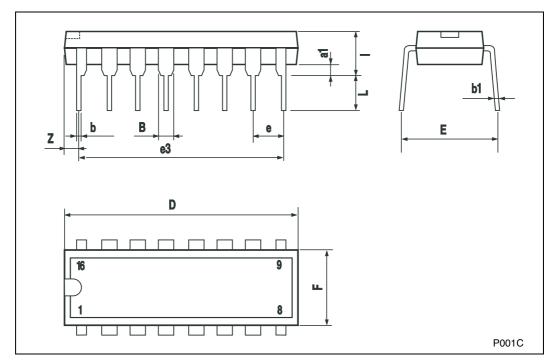
6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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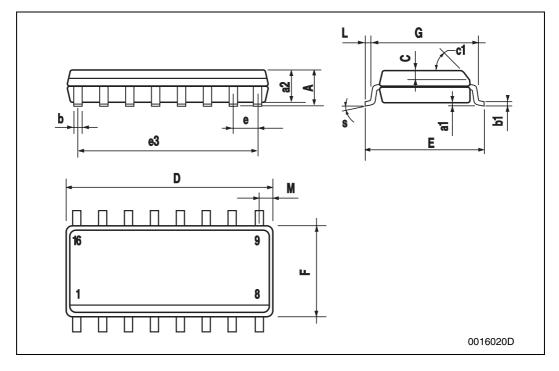
Plastic DIP-16 (0.25) MECHANICAL DATA

DIM	mm.			inch			
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	0.77		1.65	0.030		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
E		8.5			0.335		
е		2.54			0.100		
e3		17.78			0.700		
F			7.1			0.280	
1			5.1			0.201	
L		3.3			0.130		
Z			1.27			0.050	



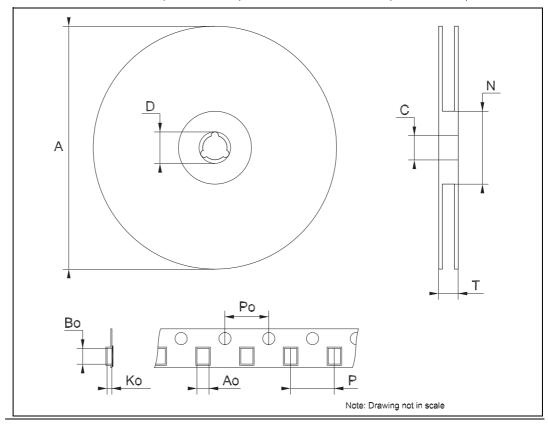
SO-16 MECHANICAL DATA

DIM.	mm.					
DIW.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			1.75			0.068
a1	0.1		0.25	0.004		0.010
a2			1.64			0.063
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)		
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024
S			8° (r	nax.)		



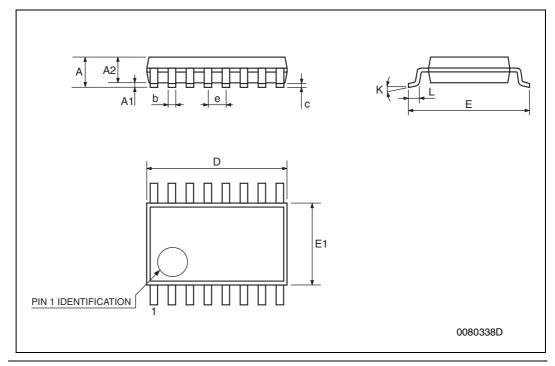
Tape &	Reel	SO-16	MECHA	NICAL	DATA
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DIM.	mm.			inch		
Diwi.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.45		6.65	0.254		0.262
Во	10.3		10.5	0.406		0.414
Ko	2.1		2.3	0.082		0.090
Ро	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319

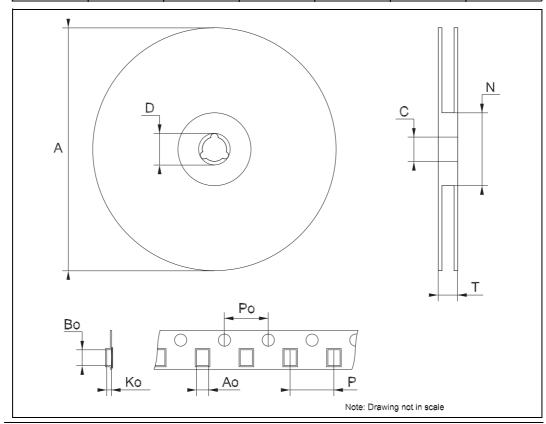


TSSOP16 MECHANICAL DATA

DIM		mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.		
Α			1.2			0.047		
A1	0.05		0.15	0.002	0.004	0.006		
A2	0.8	1	1.05	0.031	0.039	0.041		
b	0.19		0.30	0.007		0.012		
С	0.09		0.20	0.004		0.0079		
D	4.9	5	5.1	0.193	0.197	0.201		
E	6.2	6.4	6.6	0.244	0.252	0.260		
E1	4.3	4.4	4.48	0.169	0.173	0.176		
е		0.65 BSC			0.0256 BSC			
К	0°		8°	0°		8°		
L,	0.45	0.60	0.75	0.018	0.024	0.030		



DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
Α			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Во	5.3		5.5	0.209		0.217
Ко	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



STPIC6D595 Revision history

7 Revision history

Table 7. Document revision history

Date	Revision	Changes	
20-Jun-2007	1	First release	
06-Sep-2007	2	Change from Preliminary to final version	

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